

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	87	((wave adj function) or wavefunction) with space	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/07 14:54
S2	3098	257/14,9,31,34,663,200,32,33. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 15:49
S3	391	((wave adj function) or wavefunction) with well	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/07 14:54
S4	332	((wave adj function) or wavefunction) with well and quantum	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/07 14:55
S5	196	((wave adj function) or wavefunction) with well and quantum and potential	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 12:32
S6	51	((wave adj function) or wavefunction) same qubit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 11:05
S7	11	(two adj planes) with electron with between	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/08 12:41
S8	3	((wave adj function) or wavefunction) same qubit and phonon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 15:49
S9	48	((wave adj function) or wavefunction) with well and quantum and potential and phonon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 12:32

S10	2	((wave adj function) or wavefunction) with well and quantum and potential and (phonon same switch\$2)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 12:35
S11	2	((wave adj function) or wavefunction) and (quantum adj computer) and (phonon same switch\$2)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/16 12:38
S12	1075	mosfet and (boron same drain same source) and (gate same (contact or electrode)) and ((contact or electrode) with two)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 14:26
S13	3482	257/14,9,31,34,663,200,32,33.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 14:19
S14	10	S12 and S13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 14:19
S15	940	mosfet and (boron same drain same source) and (gate same (contact or electrode)) and ((contact or electrode) with two) and (channel with gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 14:27
S16	0	mosfet and (boron same drain same source) and (gate same (contact or electrode)) and ((contact or electrode) with two) and (channel adj in adj gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 14:26
S17	858	mosfet and (boron same drain same source) and (gate same (contact or electrode)) and ((contact or electrode) with two) and (channel with gate) and "257"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 14:28
S18	169	mosfet and (boron same drain same source) and (gate same (contact or electrode)) and ((contact or electrode) with two) and (contacts with two with gate) and "257"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 14:43

S19	132	mosfet and (boron same drain same source) and (gate same (contact or electrode)) and ((contact or electrode) with two) and (contacts with two with gate) and "257"/\$.ccls. and (polysilicon with gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 15:17
S20	0	two adj contacts adj on adj gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 15:18
S21	13	two adj contacts adj gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 16:05
S22	1	dual adj contact adj gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/21 16:05
S23	2	"4906583".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/24 14:49
S24	4271	(quantum adj dot)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 15:49
S25	3484	257/14,9,31,34,663,200,32,33. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 15:49
S26	229	S24 and S25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 15:52